

Description

The 9DBU0731 is a member of IDT's 1.5V Ultra-Low-Power (ULP) PCIe family. The device has 7 output enables for clock management, and 3 selectable SMBus addresses.

Recommended Application

1.5V PCIe Gen1-2-3 Fanout Buffer (FOB)

Output Features

- 7 – 1–167MHz Low-Power (LP) HCSL DIF pairs

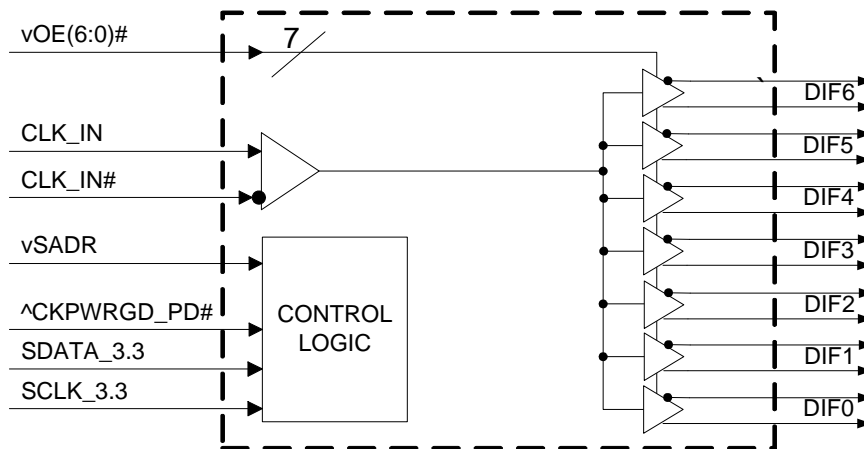
Key Specifications

- DIF *additive* cycle-to-cycle jitter < 5ps
- DIF output-to-output skew < 60ps
- DIF *additive* phase jitter is < 300fs rms for PCIe Gen3
- DIF *additive* phase jitter < 350s rms for SGMII

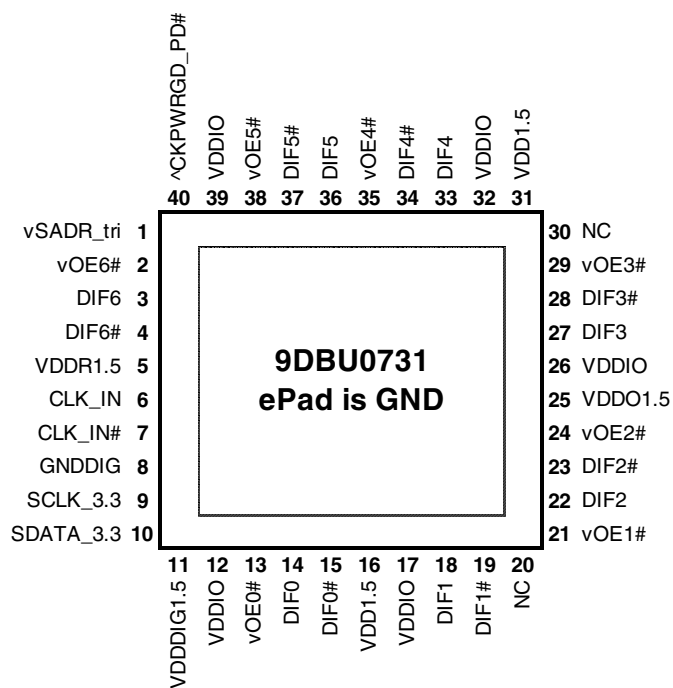
Features/Benefits

- LP-HCSL outputs; save 14 resistors compared to standard HCSL outputs
- 36mW typical power consumption; eliminates thermal concerns
- Outputs can optionally be supplied from any voltage between 1.05V and 1.5V; maximum power savings
- Spread Spectrum (SS) compatible; allows SS for EMI reduction
- OE# pins for each output; support DIF power management
- HCSL-compatible differential input; can be driven by common clock sources
- SMBus-selectable features; optimize signal integrity to application
 - slew rate for each output
 - differential output amplitude
- Device contains default configuration; SMBus interface not required for device operation
- 3.3V tolerant SMBus interface works with legacy controllers
- Three selectable SMBus addresses; multiple devices can easily share an SMBus segment
- 5 × 5 mm 40-VFQFPN package; minimal board space

Block Diagram



Pin Configuration



40-VFQFPN, 5mm x 5mm 0.4mm pin pitch

^prefix indicates internal Pull-Up Resistor

v prefix indicates Internal Pull-Down Resistor

SMBus Address Selection Table

	SADR	Address	+ Read/Write bit
State of SADR on first application of CKPWRGD_PD#	0	1101011	x
	M	1101100	x
	1	1101101	x

Power Management Table

CKPWRGD_PD#	CLK_IN	SMBus OEx bit	OEx# Pin	DIFx	
				True O/P	Comp. O/P
0	X	X	X	Low	Low
1	Running	0	X	Low	Low
1	Running	1	0	Running	Running
1	Running	1	1	Low	Low

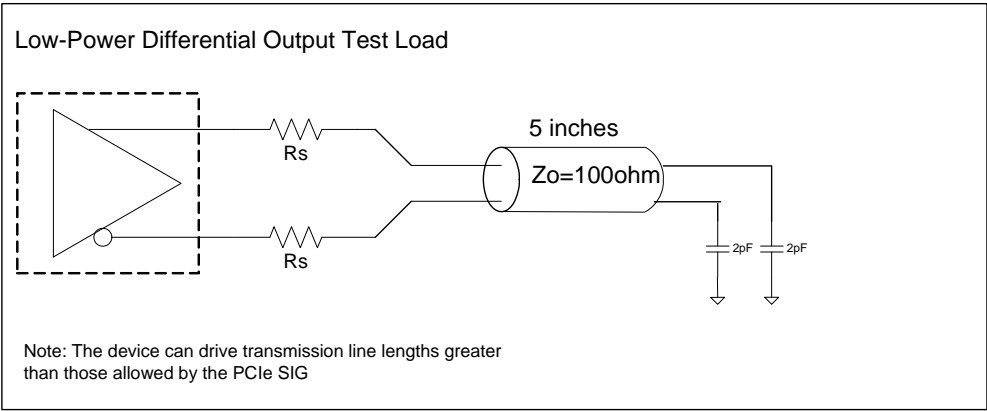
Power Connections

Pin Number		GND	Description
VDD	VDDIO		
5		41	Input receiver analog
11		8	Digital Power
16,25,31	12,17,26,32,39	41	DIF outputs, Logic

Pin Descriptions

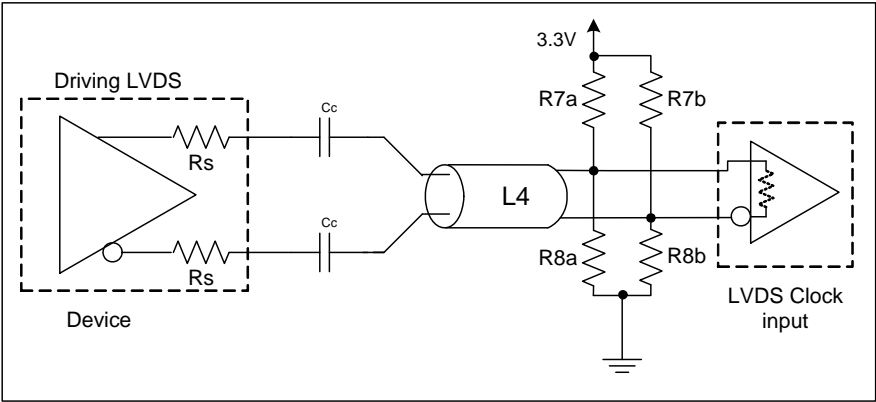
PIN #	PIN NAME	PIN TYPE	DESCRIPTION
1	vSADR_tri	LATCHED IN	Tri-level latch to select SMBus Address. It has an internal 120kohm pull down resistor. See SMBus Address Selection Table.
2	vOE6#	IN	Active low input for enabling output 6. This pin has an internal 120kohm pull-down. 1 =disable outputs, 0 = enable outputs
3	DIF6	OUT	Differential true clock output.
4	DIF6#	OUT	Differential complementary clock output.
5	VDDR1.5	PWR	1.5V power for differential input clock (receiver). This VDD should be treated as an Analog power rail and filtered appropriately.
6	CLK_IN	IN	True Input for differential reference clock.
7	CLK_IN#	IN	Complementary Input for differential reference clock.
8	GNDDIG	GND	Ground pin for digital circuitry.
9	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
10	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
11	VDDDIG1.5	PWR	1.5V digital power (dirty power)
12	VDDIO	PWR	Power supply for differential outputs
13	vOE0#	IN	Active low input for enabling output 0. This pin has an internal 120kohm pull-down. 1 =disable outputs, 0 = enable outputs
14	DIF0	OUT	Differential true clock output.
15	DIF0#	OUT	Differential complementary clock output.
16	VDD1.5	PWR	Power supply, nominally 1.5V
17	VDDIO	PWR	Power supply for differential outputs
18	DIF1	OUT	Differential true clock output.
19	DIF1#	OUT	Differential complementary clock output.
20	NC	N/A	No connection.
21	vOE1#	IN	Active low input for enabling output 1. This pin has an internal 120kohm pull-down. 1 =disable outputs, 0 = enable outputs
22	DIF2	OUT	Differential true clock output.
23	DIF2#	OUT	Differential complementary clock output.
24	vOE2#	IN	Active low input for enabling output 2. This pin has an internal 120kohm pull-down. 1 =disable outputs, 0 = enable outputs
25	VDDO1.5	PWR	Power supply for outputs, nominally 1.5V.
26	VDDIO	PWR	Power supply for differential outputs
27	DIF3	OUT	Differential true clock output.
28	DIF3#	OUT	Differential complementary clock output.
29	vOE3#	IN	Active low input for enabling output 3. This pin has an internal 120kohm pull-down. 1 =disable outputs, 0 = enable outputs
30	NC	N/A	No connection.
31	VDD1.5	PWR	Power supply, nominally 1.5V
32	VDDIO	PWR	Power supply for differential outputs
33	DIF4	OUT	Differential true clock output.
34	DIF4#	OUT	Differential complementary clock output.
35	vOE4#	IN	Active low input for enabling output 4. This pin has an internal 120kohm pull-down. 1 =disable outputs, 0 = enable outputs
36	DIF5	OUT	Differential true clock output.
37	DIF5#	OUT	Differential complementary clock output.
38	vOE5#	IN	Active low input for enabling output 5. This pin has an internal 120kohm pull-down. 1 =disable outputs, 0 = enable outputs
39	VDDIO	PWR	Power supply for differential outputs
40	^CKPWRGD_PD#	IN	Input notifies device to sample latched inputs and start up on first high assertion. Low enters Power Down Mode, subsequent high assertions exit Power Down Mode. This pin has internal 120kohm pull-up resistor.
41	EPAD	GND	Connect paddle to ground.

Test Loads



Alternate Differential Output Terminations		
Rs	Zo	Units
33	100	Ohms
27	85	

Driving LVDS



Component	Value		Note
	Receiver has termination	Receiver does not have termination	
R7a, R7b	10K ohm	140 ohm	
R8a, R8b	5.6K ohm	75 ohm	
Cc	0.1 uF	0.1 uF	
Vcm	1.2 volts	1.2 volts	

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9DBU0731. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx	Applies to VDD, VDDA and VDDIO	-0.5		2	V	1,2
Input Voltage	V _{IN}		-0.5		V _{DD} +0.5	V	1,
Input High Voltage, SMBus	V _{IHSMB}	SMBus clock and data pins			3.3	V	1
Storage Temperature	T _s		-65		150	°C	1
Junction Temperature	T _j				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 2.0V.

Electrical Characteristics–Clock Input Parameters

T_A = T_{AMB}, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Common Mode Voltage - DIF_IN	V _{COM}	Common Mode Input Voltage	200		725	mV	1
Input Swing - DIF_IN	V _{SWING}	Differential value	300		1450	mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I _{IN}	V _{IN} = V _{DD} , V _{IN} = GND	-5		5	μA	
Input Duty Cycle	d _{tin}	Measurement from differential waveform	45	50	55	%	1
Input Jitter - Cycle to Cycle	J _{DIFIn}	Differential Measurement	0		150	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

² Slew rate measured through +/-75mV window centered around differential zero

Electrical Characteristics–Input/Supply/Common Parameters–Normal Operating Conditions

TA = TAMB; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx	Supply voltage for core and analog	1.425	1.5	1.575	V	
Output Supply Voltage	VDDIO	Low Voltage Supply LP-HCSL Outputs	0.95	1.05-1.5	1.575	V	
Ambient Operating Temperature	TAMB	Commercial range	0	25	70	°C	1
		Industrial range	-40	25	85	°C	1
Input High Voltage	VIH	Single-ended inputs, except SMBus	0.75 VDD		VDD + 0.3	V	
Input Mid Voltage	VIM	Single-ended tri-level inputs ('_tri' suffix)	0.4 VDD		0.6 VDD	V	
Input Low Voltage	VIL	Single-ended inputs, except SMBus	-0.3		0.25 VDD	V	
Input Current	IIN	Single-ended inputs, VIN = GND, VIN = VDD	-5		5	μA	
	IINP	Single-ended inputs VIN = 0 V; Inputs with internal pull-up resistors VIN = VDD; Inputs with internal pull-down resistors	-200		200	μA	
Input Frequency	FIn		1		167	MHz	2
Pin Inductance	Lpin				7	nH	1
Capacitance	CIN	Logic Inputs, except DIF_IN	1.5		5	pF	1
	CINDIF_IN	DIF_IN differential clock inputs	1.5		2.7	pF	1,5
	COUT	Output pin capacitance			6	pF	1
Clk Stabilization	TSTAB	From VDD Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock			1	ms	1,2
Input SS Modulation Frequency PCIe	fMODINPCIe	Allowable Frequency for PCIe Applications (Triangular Modulation)	30		33	kHz	
Input SS Modulation Frequency non-PCIe	fMODIN	Allowable Frequency for non-PCIe Applications (Triangular Modulation)	0		66	kHz	
OE# Latency	tLATOE#	DIF start after OE# assertion DIF stop after OE# deassertion	1		3	clocks	1,3
Tdrive_PD#	tDRVPD	DIF output enable after PD# de-assertion			300	μs	1,3
Tfall	tF	Fall time of single-ended control inputs			5	ns	2
Trise	tR	Rise time of single-ended control inputs			5	ns	2
SMBus Input Low Voltage	VILSMB				0.6	V	
SMBus Input High Voltage	VIHSMB	VDDSMB = 3.3V, see note 4 for VDDSMB < 3.3V	2.1		3.3	V	4
SMBus Output Low Voltage	VOLSMB	@ IPULLUP			0.4	V	
SMBus Sink Current	IPULLUP	@ VOL	4			mA	
Nominal Bus Voltage	VDDSMB	Bus Voltage	1.425		3.3	V	
SCLK/SDATA Rise Time	tRSMB	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	tFSMB	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	fMAXSMB	Maximum SMBus operating frequency			400	kHz	6

¹Guaranteed by design and characterization, not 100% tested in production.

²Control input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

⁴For VDDSMB < 3.3V, VIHSMB >= 0.8xVDDSMB

⁵DIF_IN input

⁶The differential input clock must be running for the SMBus to be active

Electrical Characteristics–DIF Low-Power HCSL Outputs

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	dV/dt	Scope averaging on, fast setting	1.4	2.3	3.5	V/ns	1,2,3
	dV/dt	Scope averaging on, slow setting	0.9	1.5	2.5	V/ns	1,2,3
Slew rate matching	Δ dV/dt	Slew rate matching, Scope averaging on		9.3	20	%	1,2,4
Voltage High	V _{HIGH}	Statistical measurement on single-ended signal using oscilloscope math function. (Scope averaging on)	630	750	850	mV	7
Voltage Low	V _{LOW}		-150	26	150		7
Max Voltage	V _{max}	Measurement on single ended signal using absolute value. (Scope averaging off)		763	1150	mV	7
Min Voltage	V _{min}		-300	22			7
Vswing	V _{swing}	Scope averaging off	300	1448		mV	1,2
Crossing Voltage (abs)	V _{cross_abs}	Scope averaging off	250	390	550	mV	1,5
Crossing Voltage (var)	Δ -V _{cross}	Scope averaging off		11	140	mV	1,6

¹Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Slew rate is measured through the V_{swing} voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ V_{cross} is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all V_{cross} measurements in any particular system. Note that this is a subset of V_{cross_min/max} (V_{cross} absolute) allowed. The intent is to limit V_{cross} induced modulation by setting Δ -V_{cross} to be smaller than V_{cross} absolute.

⁷ At default SMBus settings.

Electrical Characteristics–Current Consumption

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I _{DDA}	VDDO1.5+VDDR, @100MHz		2.2	3	mA	
	I _{DD}	VDD, All outputs active @100MHz		3.6	5	mA	
	I _{DDIO}	VDDIO, All outputs active @100MHz		26	31	mA	
Powerdown Current	I _{DDAPD}	VDDO1.5+VDDR, CKPWRGD_PD#=0		0.4	1	mA	2
	I _{DDPD}	VDDx, CKPWRGD_PD#=0		0.25	0.6	mA	2
	I _{DDIOPD}	VDDIO, CKPWRGD_PD#=0		0.0006	0.1	mA	2

¹ Guaranteed by design and characterization, not 100% tested in production.

² Input clock stopped.

Electrical Characteristics–Output Duty Cycle, Jitter, Skew and PLL Characteristics

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Duty Cycle Distortion	t _{DCD}	Measured differentially, @100MHz	-1	-0.2	0.5	%	1,3
Skew, Input to Output	t _{pdBYP}	V _T = 50%	2400	2862	3700	ps	1
Skew, Output to Output	t _{sk3}	V _T = 50%		30	60	ps	1,4
Jitter, Cycle to cycle	t _{jcy c-cyc}	Additive Jitter		0.1	5	ps	1,2

¹ Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Duty cycle distortion is the difference in duty cycle between the output and the input clock.

⁴ All outputs at default slew rate

Electrical Characteristics–Phase Jitter Parameters

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	INDUSTRY LIMIT	UNITS	Notes
Additive Phase Jitter	t _{jphPCleG1}	PCle Gen 1		0.1	5	N/A	ps (p-p)	1,2,3,5
	t _{jphPCleG2}	PCle Gen 2 Lo Band 10kHz < f < 1.5MHz		0.1	0.4	N/A	ps (rms)	1,2,3,4,5
		PCle Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.1	0.7	N/A	ps (rms)	1,2,3,4
	t _{jphPCleG3}	PCle Gen 3 (2-4MHz or 2-5MHz, CDR = 10MHz)		0.1	0.3	N/A	ps (rms)	1,2,3,4
	t _{jphSGMIIMO}	125MHz, 1.5MHz to 10MHz, -20dB/decade rollover < 1.5MHz, -40db/decade rolloff > 10MHz		200	250	N/A	fs (rms)	1,6
	t _{jphSGMIIM1}	125MHz, 12kHz to 20MHz, -20dB/decade rollover < 1.5MHz, -40db/decade rolloff > 10MHz		313	350	N/A	fs (rms)	1,6

¹ Guaranteed by design and characterization, not 100% tested in production.

² See <http://www.pcisig.com> for complete specs

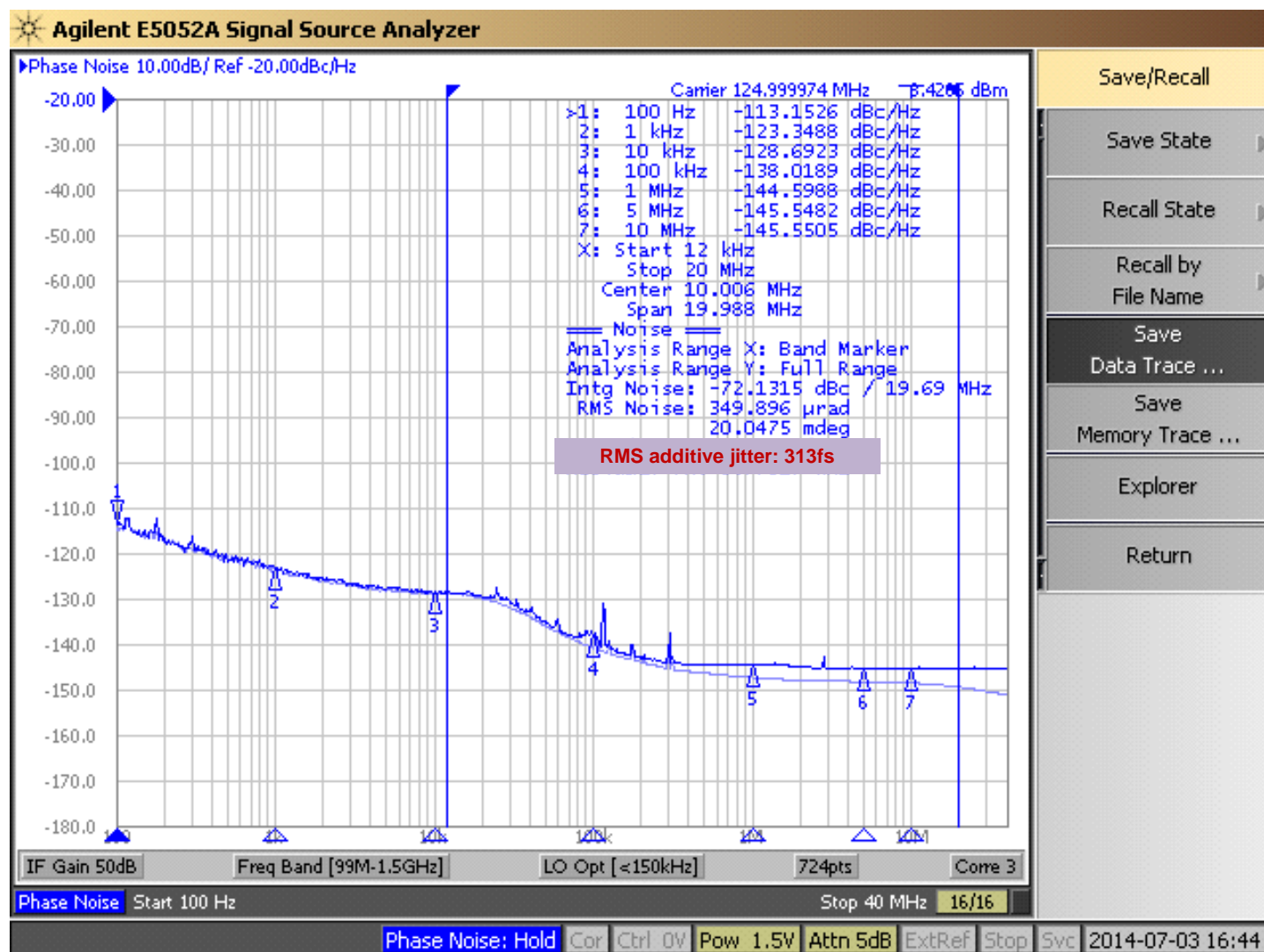
³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

⁴ For RMS figures, additive jitter is calculated by solving the following equation: Additive jitter = SQRT[(total jitter)² - (input jitter)²]

⁵ Driven by 9FGV0831 or equivalent

⁶ Rohde & Schwarz SMA100

Additive Phase Jitter Plot: 125M (12kHz to 20MHz)



General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) sends the byte count = X
- IDT clock will **acknowledge**
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will **acknowledge** each byte **one at a time**
- Controller (host) sends a stop bit

Index Block Write Operation			
Controller (Host)		X Byte	IDT (Slave/Receiver)
T	starT bit		
Slave Address			
WR	WRite		
			ACK
Beginning Byte = N			
			ACK
Data Byte Count = X			
			ACK
Beginning Byte N			
			ACK
O			O
O			O
O			O
			O
Byte N + X - 1			
			ACK
P	stoP bit		

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will **acknowledge**
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends **Byte 0 through Byte X (if X_(H) was written to Byte 8)**
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

Index Block Read Operation			
Controller (Host)			IDT (Slave/Receiver)
T	starT bit		
Slave Address			
WR	WRite		
			ACK
Beginning Byte = N			
			ACK
RT	Repeat starT		
Slave Address			
RD	ReaD		
			ACK
			Data Byte Count=X
ACK			
ACK		Beginning Byte N	
O		O	
O		O	
O		O	
O			
		Byte N + X - 1	
N	Not acknowledge		
P	stoP bit		

Note: SMBus Address is Latched on SADR pin.

SMBus Table: Output Enable Register ¹

Byte 0	Name	Control Function	Type	0	1	Default
Bit 7	DIF OE5	Output Enable	RW	Low/Low	Enabled	1
Bit 6	DIF OE4	Output Enable	RW	Low/Low	Enabled	1
Bit 5	Reserved					1
Bit 4	DIF OE3	Output Enable	RW	Low/Low	Enabled	1
Bit 3	DIF OE2	Output Enable	RW	Low/Low	Enabled	1
Bit 2	DIF OE1	Output Enable	RW	Low/Low	Enabled	1
Bit 1	Reserved					1
Bit 0	DIF OE0	Output Enable	RW	Low/Low	Enabled	1

1. A low on these bits will override the OE# pin and force the differential output Low/Low

SMBus Table: PLL Operating Mode and Output Amplitude Control Register

Byte 1	Name	Control Function	Type	0	1	Default
Bit 7	Reserved					0
Bit 6	Reserved					1
Bit 5	DIF OE6	Output Enable	RW	Low/Low	Enabled	1
Bit 4	Reserved					0
Bit 3	Reserved					1
Bit 2	Reserved					1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.55V	01 = 0.65V	1
Bit 0	AMPLITUDE 0		RW	10 = 0.7V	11 = 0.8V	0

1. A low on the DIF OE bit will override the OE# pin and force the differential output Low/Low

SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Type	0	1	Default
Bit 7	SLEWRATESEL DIF5	Adjust Slew Rate of DIF5	RW	Slow Setting	Fast Setting	1
Bit 6	SLEWRATESEL DIF4	Adjust Slew Rate of DIF4	RW	Slow Setting	Fast Setting	1
Bit 5	Reserved					1
Bit 4	SLEWRATESEL DIF3	Adjust Slew Rate of DIF3	RW	Slow Setting	Fast Setting	1
Bit 3	SLEWRATESEL DIF2	Adjust Slew Rate of DIF2	RW	Slow Setting	Fast Setting	1
Bit 2	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	Slow Setting	Fast Setting	1
Bit 1	Reserved					1
Bit 0	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	Slow Setting	Fast Setting	1

Note: See "DIF 0.7V Low-Power HCSL Outputs" table for slew rates.

SMBus Table: DIF Slew Rate Control Register

Byte 3	Name	Control Function	Type	0	1	Default
Bit 7	Reserved					1
Bit 6	Reserved					1
Bit 5	Reserved					0
Bit 4	Reserved					0
Bit 3	Reserved					0
Bit 2	Reserved					1
Bit 1	Reserved					1
Bit 0	SLEWRATESEL DIF6	Adjust Slew Rate of DIF6	RW	Slow Setting	Fast Setting	1

Note: See "DIF 0.7V Low-Power HCSL Outputs" table for slew rates.

Byte 4 is Reserved and reads back 'hFF

SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Type	0	1	Default
Bit 7	RID3	Revision ID	R	A rev = 0000		0
Bit 6	RID2		R			0
Bit 5	RID1		R			0
Bit 4	RID0		R			0
Bit 3	VID3	VENDOR ID	R	0001 = IDT		0
Bit 2	VID2		R			0
Bit 1	VID1		R			0
Bit 0	VID0		R			1

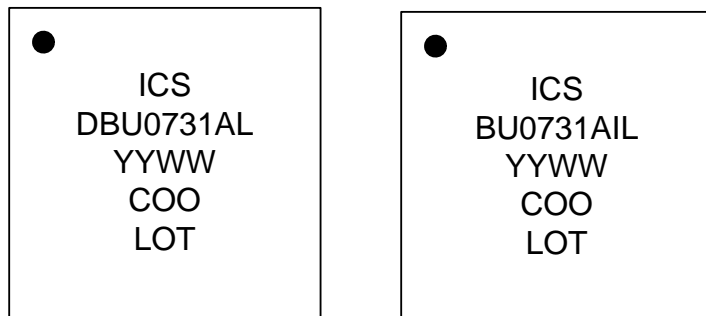
SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Type	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGx, 01 = DBx, 10 = DMx, 11= DBx w/oPLL		1
Bit 6	Device Type0		R			1
Bit 5	Device ID5	Device ID	R	000111 binary or 07 hex		0
Bit 4	Device ID4		R			0
Bit 3	Device ID3		R			0
Bit 2	Device ID2		R			1
Bit 1	Device ID1		R			1
Bit 0	Device ID0		R			1

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Type	0	1	Default
Bit 7	Reserved					0
Bit 6	Reserved					0
Bit 5	Reserved					0
Bit 4	BC4	Byte Count Programming	RW	Writing to this register will configure how many bytes will be read back, default is = 8 bytes.		0
Bit 3	BC3		RW			1
Bit 2	BC2		RW			0
Bit 1	BC1		RW			0
Bit 0	BC0		RW			0

Marking Diagrams



Notes:

1. "LOT" is the lot sequence number.
2. "COO" denotes country of origin.
3. YYWW is the last two digits of the year and week that the part was assembled.
4. Line 2: truncated part number
5. "L" denotes RoHS compliant package.
6. "I" denotes industrial temperature range device.

Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
Thermal Resistance	θ_{JC}	Junction to Case	NDG40	42	°C/W	1
	θ_{Jb}	Junction to Base		2.4	°C/W	1
	θ_{JA0}	Junction to Air, still air		39	°C/W	1
	θ_{JA1}	Junction to Air, 1 m/s air flow		33	°C/W	1
	θ_{JA3}	Junction to Air, 3 m/s air flow		28	°C/W	1
	θ_{JA5}	Junction to Air, 5 m/s air flow		27	°C/W	1

¹ePad soldered to board

Package Outline and Dimensions (NDG40)

REVIEWS

REV	DESCRIPTION	DATE	APPROVED
00	INITIAL RELEASE	5/17/16	JH

INDEX AREA
(D2/2 x E/2)

TOP VIEW

BOTTOM VIEW

SIDE VIEW

SYMBOL	DIMENSION		
	MIN	NOM	MAX
b	0.15	0.20	0.25
D	5.00 BSC		
E	5.00 BSC		
D2	3.40	3.50	3.60
E2	3.40	3.50	3.60
L	0.30	0.40	0.50
e	0.40 BSC		
N	40		
ND	10 (note 3)		
NE	10 (note 3)		
A	0.80	0.90	1.00
A1	0.00	0.02	0.05
A3	0.2 REF		
k	0.35 REF		
aaa	0.10		
bbb	0.07		
ccc	0.10		
ddd	0.05		
eee	0.08		
fff	0.10		

NOTES:

- ALL DIMENSIONING AND TOLERANCING CONFORM TO ANSI Y14.5M-1982
- ALL DIMENSIONS ARE IN MILLIMETERS.
- ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.

TOLERANCES UNLESS SPECIFIED

DECIMAL	ANGULAR
XX.XX	±1°
XX.X	±1°
XX.XX ±0.05	
XX.XX ±0.030	

APPROVALS

DATE	APPROVALS
05/31/10	
DRAWN	7700
CHECKED	

SIZE

DRAWING No.	REV
C	PSC-4292-02

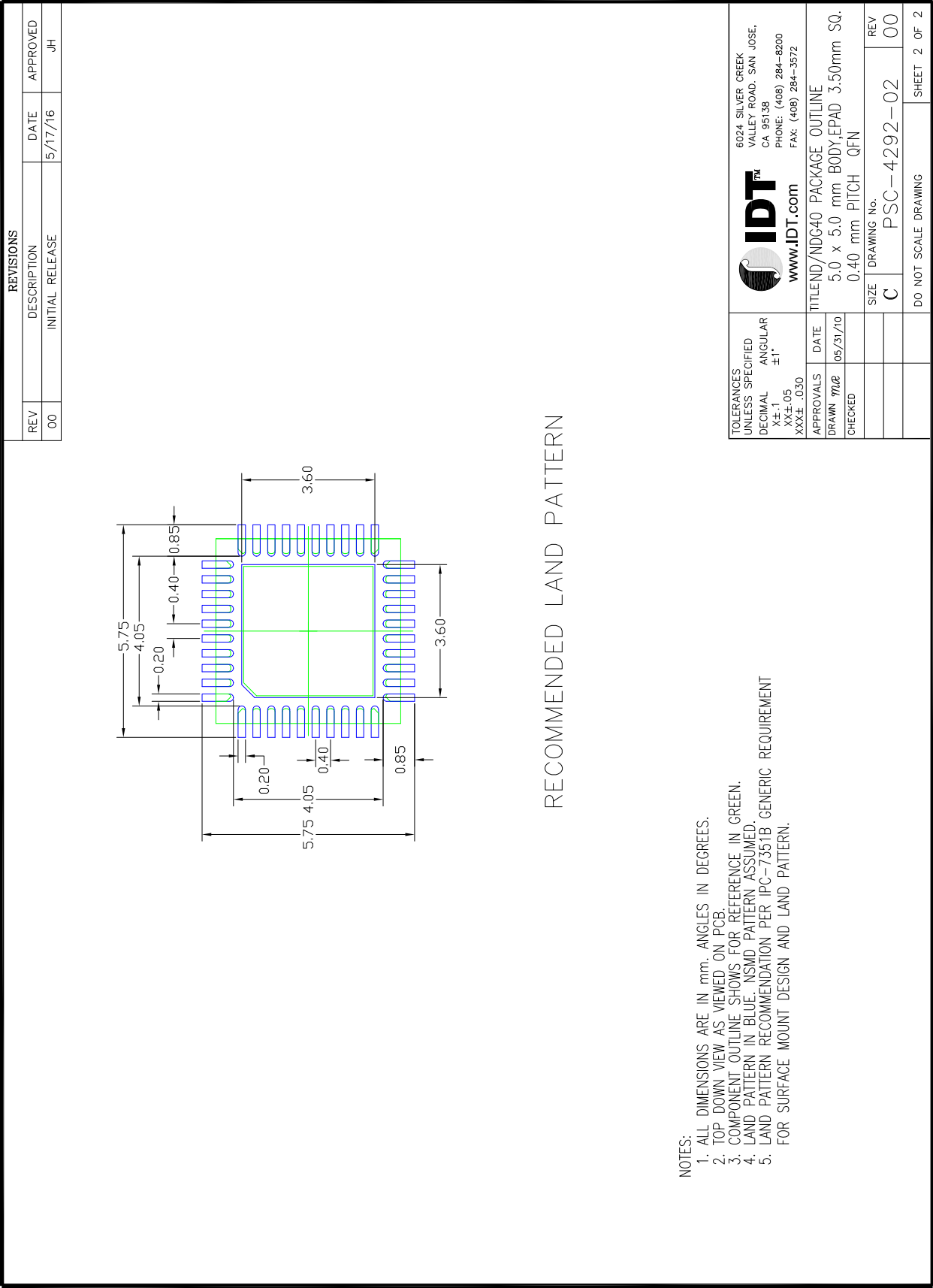
DO NOT SCALE DRAWING

SHEET 1 OF 2

6024 SILVER CREEK VALLEY ROAD, SAN JOSE, CA 95138
PHONE: (408) 284-8200
FAX: (408) 284-3572
www.IDT.com

PACKAGE OUTLINE
5.0 x 5.0 mm BODY, EPAD 3.50mm SQ.
0.40 mm PITCH QFN

Package Outline and Dimensions (NDG40), cont.



Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9DBU0731AKLF	Trays	40-pin VFQFPN	0 to +70° C
9DBU0731AKLFT	Tape and Reel	40-pin VFQFPN	0 to +70° C
9DBU0731AKILF	Trays	40-pin VFQFPN	-40 to +85° C
9DBU0731AKILFT	Tape and Reel	40-pin VFQFPN	-40 to +85° C

“LF” suffix to the part number are the Pb-Free configuration and are RoHS compliant.

“A” is the device revision designator (will not correlate with the datasheet revision).

Revision History

Rev.	Initiator	Issue Date	Description	Page #
A	RDW	7/16/2014	1. Updated electrical tables to final, and release	Various
B	RDW	9/19/2014	Updated SMBus Input High/Low parameters conditions, MAX values, and footnotes.	6
C	RDW	4/17/2015	1. Updated pin out and pin descriptions to show ePad on package connected to ground. 2. Minor updates to front page text for family consistency. 3. Updated Clock Input Parameters table to be consistent with PCIe Vswing parameter.	1-5
D	RDW	3/8/2017	1. Updated pin 25 from VDDA1.5 to VDDO1.5 to clearly indicate that this part has no PLL. 2. Removed "Bypass Mode" reference in "Output Duty Cycle..." and "Phase Jitter Parameters" tables; update note 3 under Output Duty Cycle table. 3. Changed VDDA to VDDO1.5 in Current Consumption table. 4. Updated Additive Phase Jitter conditions for PCIe Gen3.	2,3,7,8

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